TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

2SC3420

Strobe Flash Applications Audio Power Amplifier Applications

• High DC current gain: $h_{FE} = 140$ to 600 ($V_{CE} = 2$ V, $I_{C} = 0.5$ A)

 $: h_{FE} = 70 \text{ (min) } (V_{CE} = 2 \text{ V}, I_{C} = 4 \text{ A})$

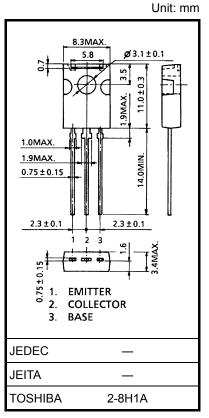
• Low saturation voltage: $V_{CE (sat)} = 1.0 \text{ V (max) (IC} = 4 \text{ A, IB} = 0.1 \text{ A})$

• High collector power dissipation: PC = 10 W ($Tc = 25^{\circ}C$),

 $P_{C} = 1.5 \text{ W (Ta} = 25^{\circ}\text{C)}$

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	50	V	
Collector-emitter voltage		V _{CES}	40	V	
		V_{CEO}	20	V	
Emitter-base voltage		V_{EBO}	8	٧	
Collector current	DC	IC	5	A	
	Pulse (Note 1)	I _{CP}	8		
Base current		ΙΒ	1	Α	
Collector power dissipation	Ta = 25°C	Da	1.5	W	
	Tc = 25°C	P _C	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	



Weight: 0.82 g (typ.)

Note 1: Pulse test: Pulse width = 10 ms (max) Duty cycle = 30% (max)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

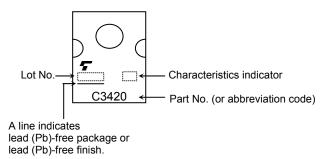
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Tc = 25°C)

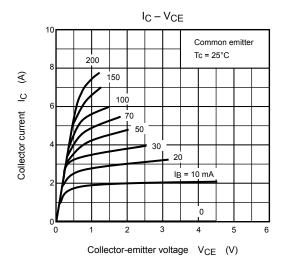
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 40 V, I _E = 0	_	_	100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 8 V, I _C = 0	_	_	100	nA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	20	_	_	V
DC current gain	h _{FE (1)} (Note 3)	V _{CE} = 2 V, I _C = 0.5 A	140	_	600	
	h _{FE} (2)	V _{CE} = 2 V, I _C = 4 A	70	_	_	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = 4 A, I _B = 0.1 A	_	_	1.0	V
Base-emitter voltage	V _{BE}	V _{CE} = 2 V, I _C = 4 A	_	_	1.5	V
Transition frequency	f _T	V _{CE} = 2 V, I _C = 0.5 A	_	100	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	40	_	pF

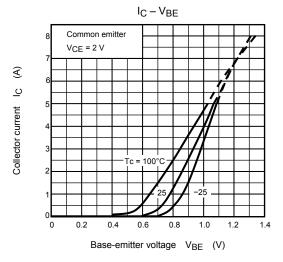
Note 3: $h_{FE\ (1)}$ classification Y: 140 to 240, GR: 200 to 400, BL: 300 to 600

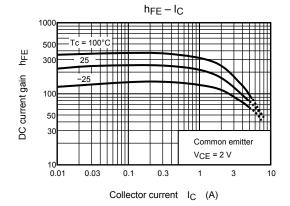
Marking

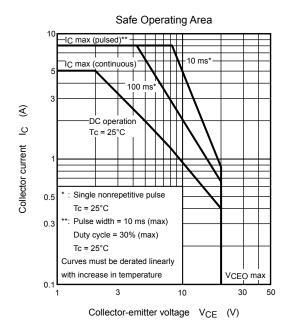


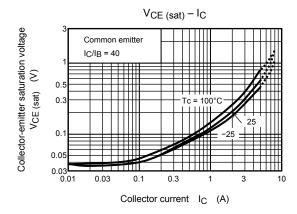
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